Thyristor Module

V_{RRM}	=	2x 1600 V
I_{TAV}	=	700 A
V_T	=	1.11 V

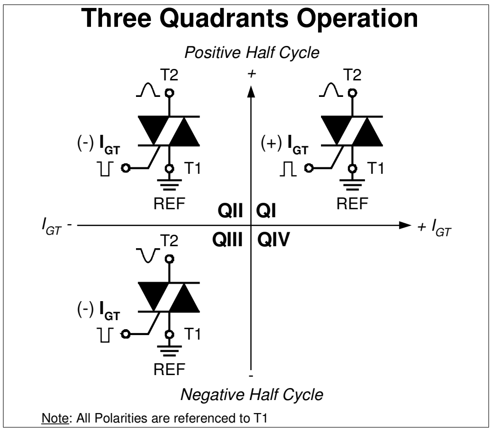
Phase leg
optional usage as Dual Thyristor Triac

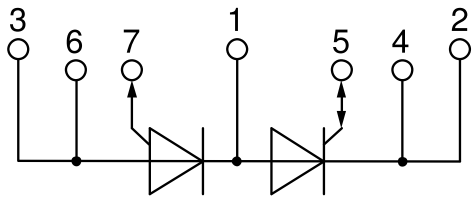
Part number

MCMA700P1600NCA

Backside: isolated

E72873





Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al2O3-ceramic
- Gate current polarities
  - upper SCR (2 -> 1) = positive/negative
  - lower SCR (1 -> 3) = negative

Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

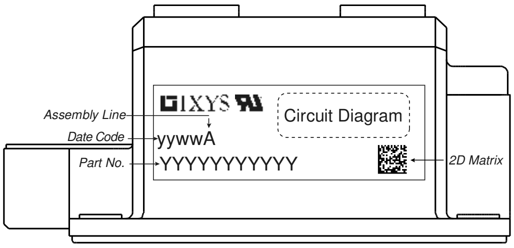
Package: ComPack

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Base plate: Copper internally DCB isolated
- Advanced power cycling
- Phase Change Material available

Rectifier

Symbol	Definition	Conditions		min.	typ.	max.	Unit
				Ratings			
$V_{RSM/DSM}$	*max. non-repetitive reverse/forward blocking voltage*		T_{VJ} = 25°C			1700	V
$V_{RRM/DRM}$	*max. repetitive reverse/forward blocking voltage*		T_{VJ} = 25°C			1600	V
$I_{R/D}$	*reverse current, drain current*	$V_{R/D}$ = 1600 V	T_{VJ} = 25°C			2	mA
		$V_{R/D}$ = 1600 V	T_{VJ} = 125°C			40	mA
V_T	*forward voltage drop*	I_T = 700 A	T_{VJ} = 25°C			1.16	V
		I_T = 1400 A				1.41	V
		I_T = 700 A	T_{VJ} = 125°C			1.11	V
		I_T = 1400 A				1.41	V
I_{TAV}	*average forward current*	T_C = 85°C	T_{VJ} = 140°C			700	A
$I_{T(RMS)}$	*RMS forward current*	180° sine				1100	A
V_{T0}	*threshold voltage*	*for power loss calculation only*	T_{VJ} = 140°C			0.82	V
r_T	*slope resistance*					0.4	mΩ
R_{thJC}	*thermal resistance junction to case*					0.05	K/W
R_{thCH}	*thermal resistance case to heatsink*				0.020		K/W
P_{tot}	*total power dissipation*		T_C = 25°C			2300	W
I_{TSM}	*max. forward surge current*	t = 10 ms; (50 Hz), sine	T_{VJ} = 45°C			19.0	kA
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			20.5	kA
		t = 10 ms; (50 Hz), sine	T_{VJ} = 140°C			16.2	kA
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			17.4	kA
I^2t	*value for fusing*	t = 10 ms; (50 Hz), sine	T_{VJ} = 45°C			1.81	MA^2s
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			1.75	MA^2s
		t = 10 ms; (50 Hz), sine	T_{VJ} = 140°C			1.30	MA^2s
		t = 8,3 ms; (60 Hz), sine	V_R = 0 V			1.27	MA^2s
C_J	*junction capacitance*	V_R = 400 V f = 1 MHz	T_{VJ} = 25°C		876		pF
P_{GM}	*max. gate power dissipation*	t_P = 30 µs	T_C = 140°C			240	W
		t_P = 300 µs				120	W
P_{GAV}	*average gate power dissipation*					40	W
$(di/dt)_{cr}$	*critical rate of rise of current*	T_{VJ} = 140 °C; f = 50 Hz	repetitive, I_T = 2100 A			100	A/µs
		t_P = 200 µs; di_G/dt = 1 A/µs;					
		I_G = 1 A; V = ⅔ V_{DRM}	non-repet., I_T = 700 A			500	A/µs
$(dv/dt)_{cr}$	*critical rate of rise of voltage*	V = ⅔ V_{DRM}	T_{VJ} = 140°C			1000	V/µs
		R_{GK} = ∞; method 1 (linear voltage rise)					
V_{GT}	*gate trigger voltage*	V_D = 6 V	T_{VJ} = 25°C			2	V
			T_{VJ} = -40°C			3	V
I_{GT}	*gate trigger current*	V_D = 6 V	T_{VJ} = 25°C			± 300	mA
			T_{VJ} = -40°C			± 400	mA
V_{GD}	*gate non-trigger voltage*	V_D = ⅔ V_{DRM}	T_{VJ} = 140°C			0.25	V
I_{GD}	*gate non-trigger current*					± 10	mA
I_L	*latching current*	t_p = 30 µs	T_{VJ} = 25 °C			400	mA
		I_G = 1 A; di_G/dt = 1 A/µs					
I_H	*holding current*	V_D = 6 V R_{GK} = ∞	T_{VJ} = 25 °C			300	mA
t_{gd}	*gate controlled delay time*	V_D = ½ V_{DRM}	T_{VJ} = 25 °C			2	µs
		I_G = 1 A; di_G/dt = 1 A/µs					
t_q	*turn-off time*	V_R = 100 V; I_T = 700 A; V = ⅔ V_{DRM}	T_{VJ} = 125 °C		350		µs
		di/dt = 10 A/µs dv/dt = 50 V/µs	t_p = 200 µs				

Package ComPack			Ratings			
Symbol	**Definition**	**Conditions**	**min.**	**typ.**	**max.**	**Unit**
I_{RMS}	*RMS current*	per terminal			1200	A
T_{VJ}	*virtual junction temperature*		-40		140	°C
T_{op}	*operation temperature*		-40		125	°C
T_{stg}	*storage temperature*		-40		125	°C
Weight				500		g
M_D	*mounting torque*		3		5	Nm
M_T	*terminal torque*		12		14	Nm
$d_{Spp/App}$	*creepage distance on surface | striking distance through air*	*terminal to terminal*	21.0			mm
$d_{Spb/Apb}$		*terminal to backside*	18.0			mm
V_{ISOL}	*isolation voltage*	t = 1 second; 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	4800			V
		t = 1 minute	4000			V



Part description

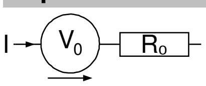
M = Module
C = Thyristor (SCR)
M = Thyristor
A = (up to 1800V)
700 = Current Rating [A]
P = Phase leg
1600 = Reverse Voltage [V]
N = Three Quadrants operation: QI - QIII
CA = ComPack

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCMA700P1600NCA	MCMA700P1600NCA	Box	3	515494

Similar Part	Package	Voltage class
MCMA700P1600CA	ComPack	1600

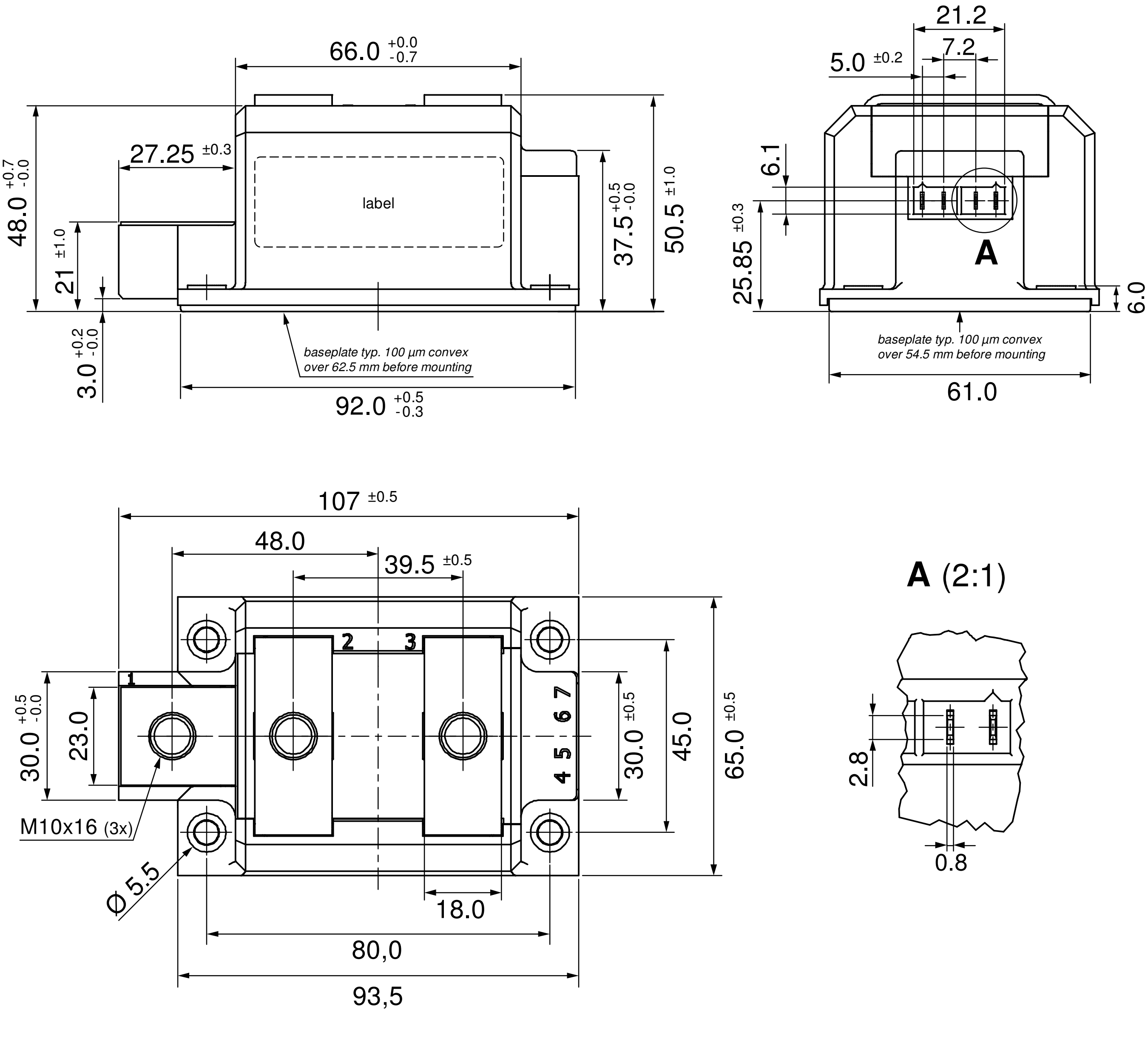
Equivalent Circuits for Simulation

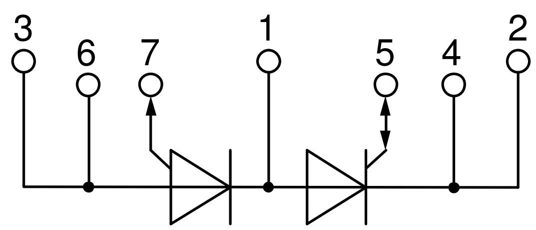
** on die level* $T_{VJ} = 140\,°C$



		Thyristor	
$V_{0\,max}$	*threshold voltage*	0.82	V
$R_{0\,max}$	*slope resistance **	0.21	mΩ

Outlines ComPack





Thyristor

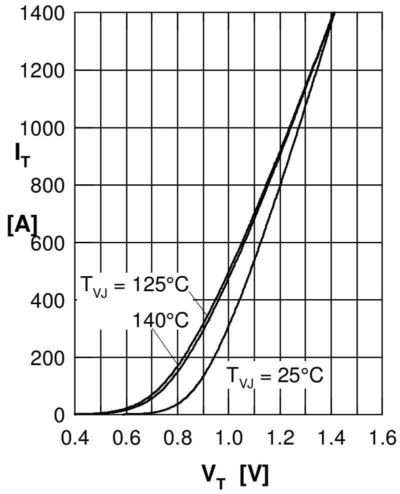


Fig. 1 Forward characteristics

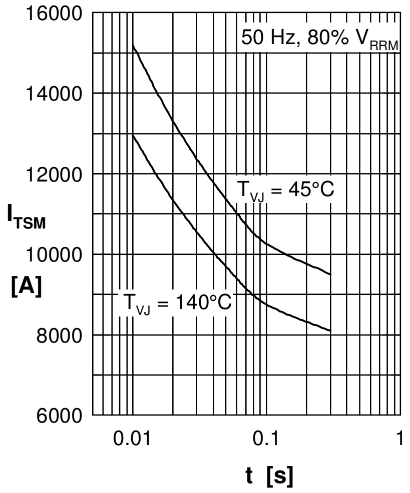


Fig. 2 Surge overload current
I_{TSM}: crest value, t: duration

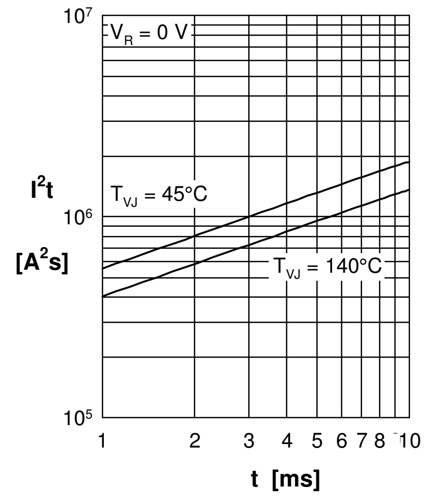


Fig. 3 I^2t versus time (1-10 s)

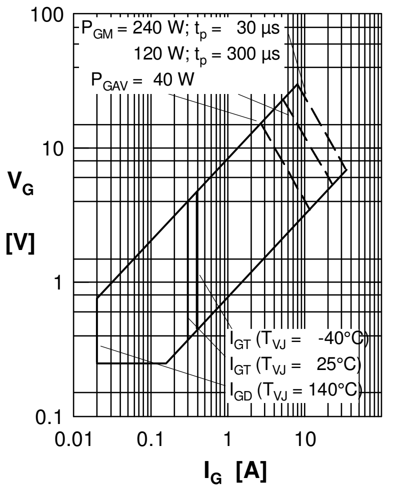


Fig. 4 Gate voltage & gate current

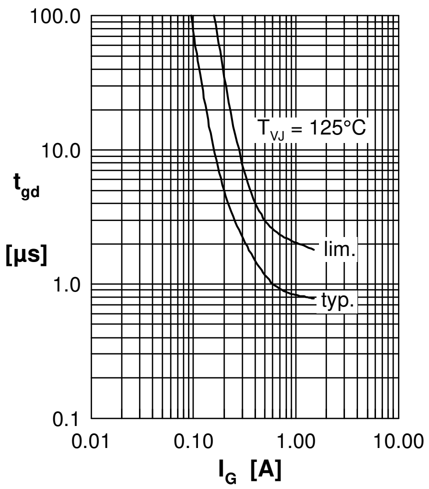


Fig. 5 Gate controlled delay time t_{gd}

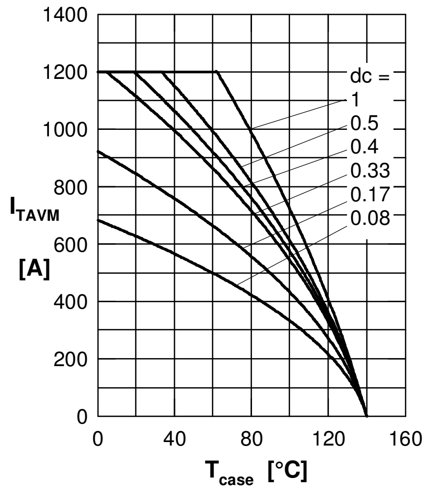


Fig. 6 Max. forward current at case temperature

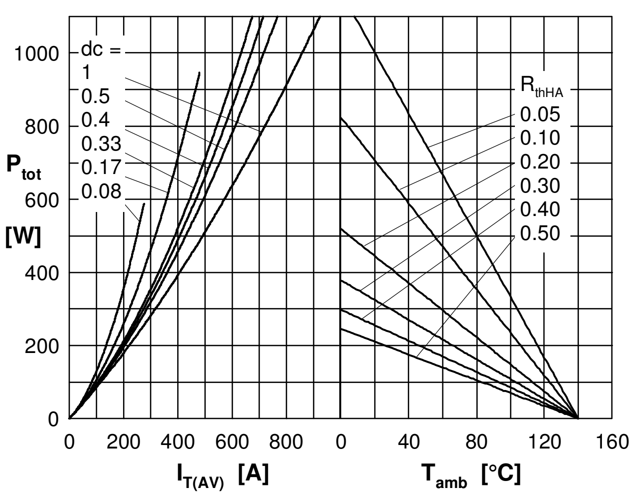


Fig. 7a Power dissipation versus direct output current
Fig. 7b and ambient temperature

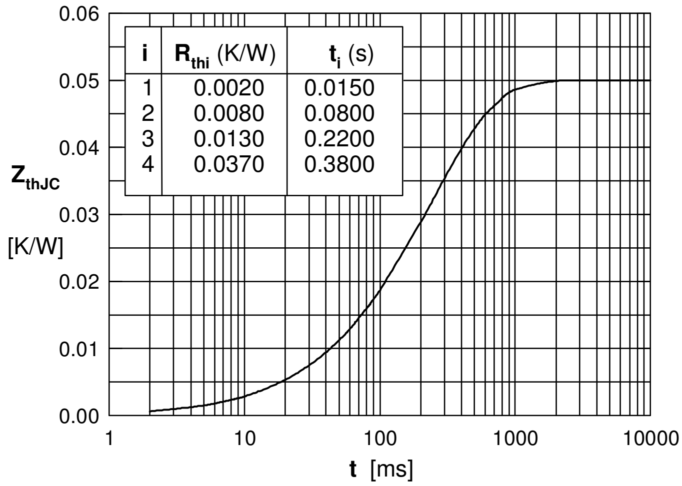


Fig. 8 Transient thermal impedance junction to case